

STB100N10F7, STD100N10F7, STF100N10F7, STP100N10F7

N-channel 100 V, 0.0068 Ω typ., 80 A, STripFET™ VII DeepGATE™ Power MOSFET in D²PAK, DPAK, TO-220FP and TO-220

Datasheet - production data

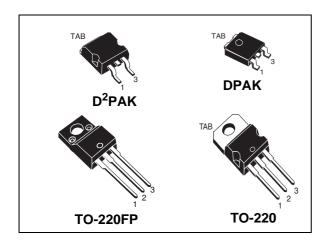
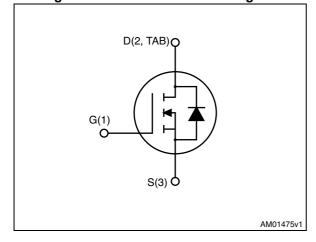


Figure 1. Internal schematic diagram



Features

Order codes	V _{DS}	R _{DS(on)} max	I _D	P _{TOT}
STB100N10F7			80 A	120 W
STD100N10F7	100.1/	0.008 Ω	80 A	120W
STF100N10F7	100 V	0.008 12	45 A	30 W
STP100N10F7			80A	150 W

- Ultra low on-resistance
- 100% avalanche tested

Applications

· Switching applications

Description

These devices utilize the 7th generation of design rules of ST's proprietary STripFETTM technology, with a new gate structure. The resulting Power MOSFET exhibits the lowest $R_{DS(on)}$ in all packages.

Table 1. Device summary

Order codes	Marking	Packages	Packaging
STB100N10F7		D ² PAK	Tape and reel
STD100N10F7	100N10F7 -	DPAK	Tape and reel
STF100N10F7		TO-220FP	Tube
STP100N10F7		TO-220	Tube

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1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	DPAK	TO-220FP	TO-220 D ² PAK	Unit
V _{DS}	Drain-source voltage		100		V
V _{GS}	Gate-source voltage	± 20			V
I _D	Drain current (continuous) at T _C = 25 °C	80	45 ⁽¹⁾	80	Α
I _D	Drain current (continuous) at T _C = 100 °C	62	32 ⁽¹⁾	70	Α
I _{DM} ⁽²⁾	Drain current (pulsed)	320	180	320	Α
P _{TOT} (1)	Total dissipation at T _C = 25 °C	120	30	150	W
T _J	Operating junction temperature	55 to 175		°C	
T _{stg}	Storage temperature		-55 10 175		°C

^{1.} This value is limited by package.

Table 3. Thermal resistance

Symbol	Parameter	Value					
Symbol	Farameter	D ² PAK	DPAK	TO-220FP	TO-220	Unit	
R _{thj-case}	Thermal resistance junction-case	1	1.25	5	1	°C/W	
R _{thj-amb}	Thermal resistance junction- ambient			62.50		°C/W	
R _{thj-pcb} (1)	Thermal resistance junction-pcb	30	50			°C/W	

^{1.} When mounted on FR-4 board of 1inch 2 , 2oz Cu, t < 10 sec

Table 4. Avalanche characteristics

Symbol	Parameter	Value	Unit
l ⊢	Single pulse avalanche energy (T $_{\rm J}$ = 25 °C, L = 3.5 mH, I $_{\rm AS}$ = 15 A, V $_{\rm DD}$ = 50 V, V $_{\rm GS}$ = 10 V)	400	mJ

^{2.} Pulse width limited by safe operating area.

2 Electrical characteristics

(T_{CASE}=25 °C unless otherwise specified)

Table 5. On/off states

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _{(BR)DSS}	Drain-source breakdown voltage (V _{GS} = 0)	I _D = 250 μA	100		-	٧
I _{DSS}	Zero gate voltage drain current (V _{GS} = 0)	V _{DS} = 100 V V _{DS} = 100 V; T _C =125 °C			1 100	μA μA
I _{GSS}	Gate body leakage current (V _{DS} = 0)	V _{GS} = 20 V			100	nA
V _{GS(th)}	Gate threshold voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.5		4.5	٧
	Static drain-source on-	For D ² PAK, DPAK and TO-220				
R _{DS(on)}	resistance	V_{GS} = 10 V, I_{D} = 40 A For TO-220-FP V_{GS} = 10 V, I_{D} = 22.5 A		0.0068	0.008	Ω

Table 6. Dynamic

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
C _{iss}	Input capacitance		-	4369	-	pF
C _{oss}	Output capacitance	V _{DS} =50 V, f=1 MHz,	-	823	-	pF
C _{rss}	Reverse transfer capacitance	V _{GS} =0	-	36	-	pF
Qg	Total gate charge	V _{DD} =50 V, I _D = 80 A	-	61	-	nC
Q _{gs}	Gate-source charge	V _{GS} =10 V	-	26	-	nC
Q _{gd}	Gate-drain charge	Figure 18	-	13	-	nC

Table 7. Switching times

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t _{d(on)}	Turn-on delay time		-	27	-	ns
t _r	Rise time	V _{DD} =50 V, I _D = 40 A, R _G =4.7 Ω, V _{GS} = 10 V	-	40	-	ns
t _{d(off)}	Turn-off delay time	n _G =4.7 52, v _{GS} = 10 v <i>Figure 17</i>	-	46	-	ns
t _f	Fall time		-	15	-	ns

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Table 8. Source drain diode

Symbol	Parameter	Test conditions	Min	Тур.	Max	Unit
I _{SD}	Source-drain current		-		80	Α
I _{SDM} ⁽¹⁾	Source-drain current (pulsed)		-		320	Α
V _{SD} ⁽²⁾	Forward on voltage	I _{SD} = 80 A, V _{GS} =0	-		1.2	٧
t _{rr}	Reverse recovery time	I _{SD} = 80 A,	-	77		ns
Q _{rr}	Reverse recovery charge	$di/dt = 100 A/\mu s$,	-	146		nC
I _{RRM}	Reverse recovery current	V _{DD} =80 V, T _j =150 °C	-	4		Α

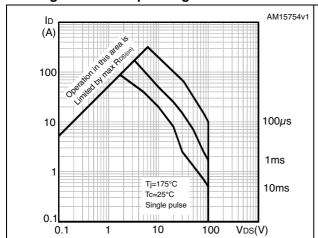
^{1.} Pulse width limited by safe operating area

^{2.} Pulsed: pulse duration=300 μ s, duty cycle 1.5%

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area for DPAK

Figure 3. Thermal impedance for DPAK



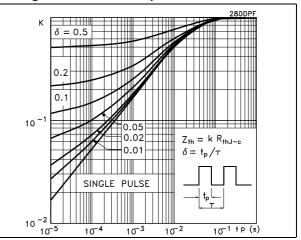
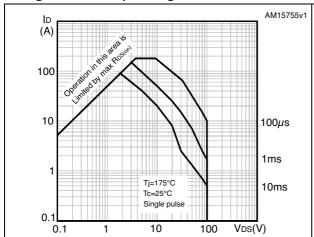


Figure 4. Safe operating area for TO-220FP

Figure 5. Thermal impedance for TO-220FP



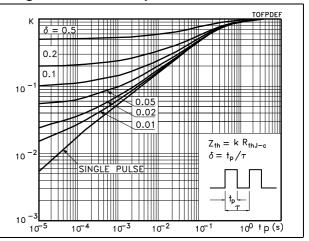
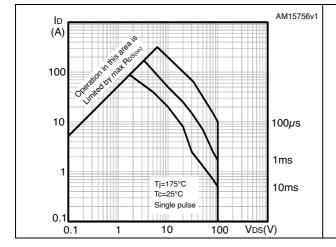
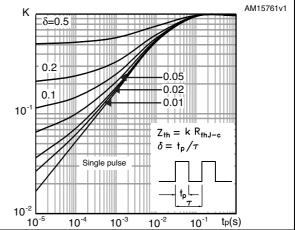


Figure 6. Safe operating area for D²PAK and TO-220

Figure 7. Thermal impedance for D²PAK and TO-220





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Figure 8. Output characteristics

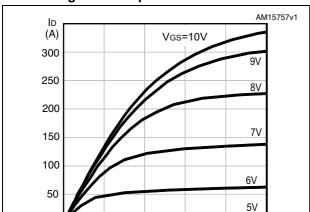


Figure 9. Transfer characteristics

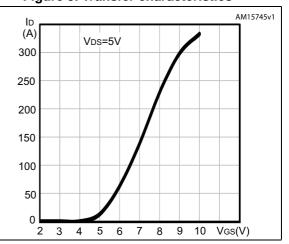
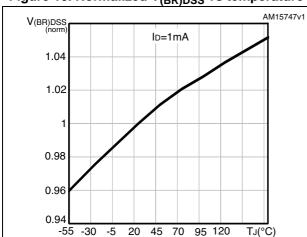


Figure 10. Normalized $V_{(BR)DSS}$ vs temperature

V_{DS}(V)

Figure 11. Static drain-source on-resistance



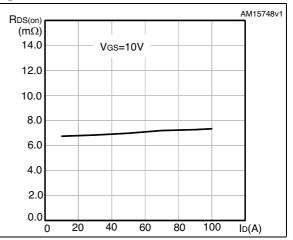


Figure 12. Gate charge vs gate-source voltage

VGS (V) VDD=50V ID=80A ID=80A OO Qg(nC)

Figure 13. Capacitance variations

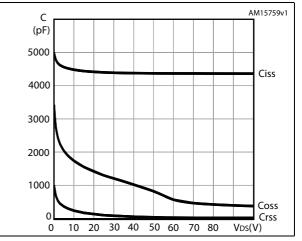


Figure 14. Normalized gate threshold voltage vs temperature

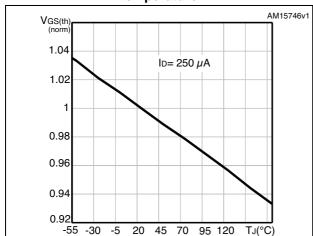


Figure 15. Normalized on-resistance vs temperature

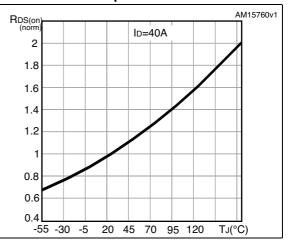
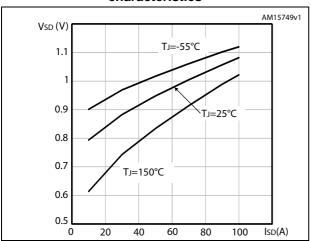


Figure 16. Source-drain diode forward characteristics



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3 Test circuits

Figure 17. Switching times test circuit for resistive load

Figure 18. Gate charge test circuit

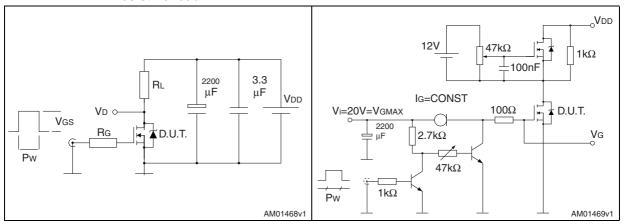


Figure 19. Test circuit for inductive load switching and diode recovery times

Figure 20. Unclamped inductive load test circuit

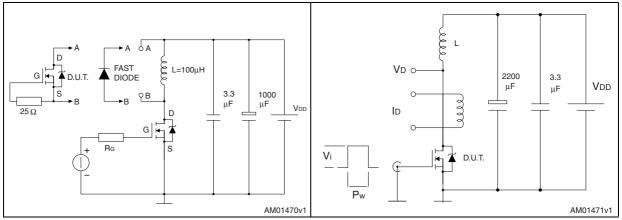
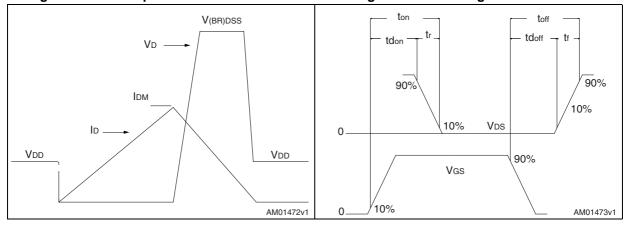


Figure 21. Unclamped inductive waveform

Figure 22. Switching time waveform



4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

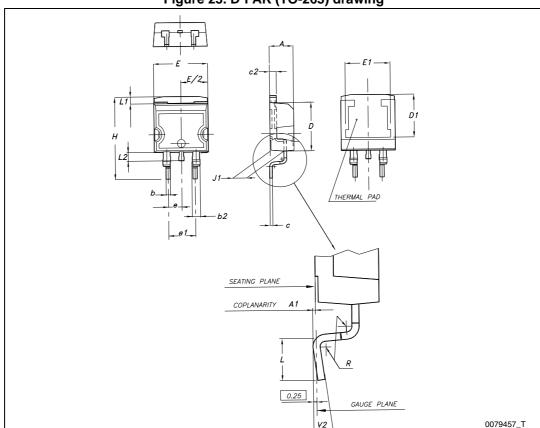


Figure 23. D²PAK (TO-263) drawing

16.90

12.20

5.08

9.75

Footprint

Figure 24. D²PAK footprint^(a)

a. All dimension are in millimeters



Table 9. DPAK (TO-252) mechanical data

		mm	
Dim.	Min.	Тур.	Max.
Α	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
С	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1		5.10	
E	6.40		6.60
E1		4.70	
е		2.28	
e1	4.40		4.60
Н	9.35		10.10
L	1.00		1.50
(L1)		2.80	
L2		0.80	
L4	0.60		1.00
R		0.20	
V2	0°		8°

E -THERMAL PAD c2 *L2* D1 **b**(2x) R C SEATING PLANE (L1) *V2* GAUGE PL 0,25 0068772_K

Figure 25. DPAK (TO-252) drawing

Figure 26. DPAK footprint (b)

b. All dimensions are in millimeters

Table 10. TO-220FP mechanical data

Dim		mm				
Dim.	Min.	Тур.	Max.			
А	4.4		4.6			
В	2.5		2.7			
D	2.5		2.75			
E	0.45		0.7			
F	0.75		1			
F1	1.15		1.70			
F2	1.15		1.70			
G	4.95		5.2			
G1	2.4		2.7			
Н	10		10.4			
L2		16				
L3	28.6		30.6			
L4	9.8		10.6			
L5	2.9		3.6			
L6	15.9		16.4			
L7	9		9.3			
Dia	3		3.2			

-*B*-Dia L6 L2 *L7* L3 F1 **L4** F2 Ε -G1_ 7012510_Rev_K_B

Figure 27. TO-220FP drawing

Table 11. TO-220 type A mechanical data

	mm				
Dim.	Min.	Тур.	Max.		
А	4.40		4.60		
b	0.61		0.88		
b1	1.14		1.70		
С	0.48		0.70		
D	15.25		15.75		
D1		1.27			
E	10		10.40		
е	2.40		2.70		
e1	4.95		5.15		
F	1.23		1.32		
H1	6.20		6.60		
J1	2.40		2.72		
L	13		14		
L1	3.50		3.93		
L20		16.40			
L30		28.90			
ØP	3.75		3.85		
Q	2.65		2.95		

Figure 28. TO-220 type A drawing

5 Packaging mechanical data

Table 12. D²PAK (TO-263) tape and reel mechanical data

Таре				Reel		
Dim.	mm		Dim.	mm		
	Min.	Max.	Dim.	Min.	Max.	
A0	10.5	10.7	Α		330	
В0	15.7	15.9	В	1.5		
D	1.5	1.6	С	12.8	13.2	
D1	1.59	1.61	D	20.2		
Е	1.65	1.85	G	24.4	26.4	
F	11.4	11.6	N	100		
K0	4.8	5.0	Т		30.4	
P0	3.9	4.1				
P1	11.9	12.1		Base qty	1000	
P2	1.9	2.1		Bulk qty	1000	
R	50					
Т	0.25	0.35				
W	23.7	24.3				

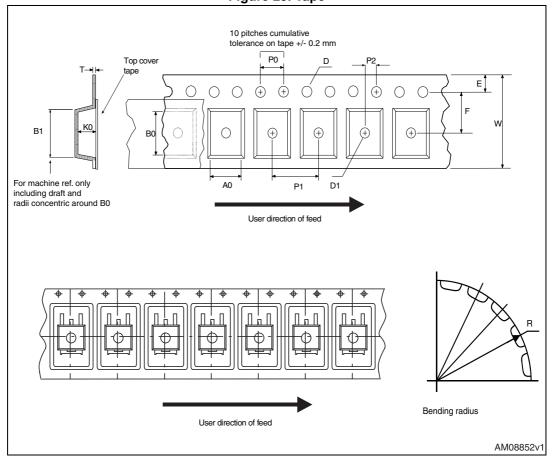
Table 13. DPAK (TO-252) tape and reel mechanical data

Tape				Reel		
Dim	mm		Dim	mm		
	Min.	Max.	Dim.	Min.	Max.	
A0	6.8	7	Α		330	
В0	10.4	10.6	В	1.5		
B1		12.1	С	12.8	13.2	
D	1.5	1.6	D	20.2		
D1	1.5		G	16.4	18.4	
Е	1.65	1.85	N	50		
F	7.4	7.6	Т		22.4	
K0	2.55	2.75				
P0	3.9	4.1		Base qty.	2500	
P1	7.9	8.1		Bulk qty.	2500	

Table 13. DPAK (TO-252) tape and reel mechanical data (continued)

Tape			Reel		
Dim.	mm		Dim	mm	
Dim.	Min.	Max.	Dim.	Min.	Max.
P2	1.9	2.1			
R	40				
Т	0.25	0.35			
W	15.7	16.3			

Figure 29. Tape



REEL DIMENSIONS

T

40mm min.

Access hole

At slot location

Tape slot in core for tape start 25 mm min. width

AM08851v2

Figure 30. Reel

6 Revision history

Table 14. Document revision history

Date	Revision	Changes	
05-Oct-2012	1	First release.	
07-Feb-2013	2	 Inserted device in TO-220FP. Updated title and features on the cover page, Table 1: Device summary, Table 2: Absolute maximum ratings, Table 3: Thermal resistance and Table 5: On/off states accordingly. Updated Table 6: Dynamic, Table 7: Switching times, Table 8: Source drain diode and Section 4: Package mechanical data. Added Section 5: Packaging mechanical data. 	
29-Apr-2013	3	 Modified: the entire typical values in <i>Table 6</i>, t_f typical value in <i>Table 7</i>, V_{SD} and typical values for t_{rr}, q_{rr}, I_{RRM} Inserted: <i>Table 4: Avalanche characteristics</i> and <i>Section 2.1: Electrical characteristics (curves)</i> Minor text changes 	
25-Nov-2013	4	 Inserted device in D²PAK. Updated title and features on the cover page, Table 1: Device summary, Table 2: Absolute maximum ratings, Table 3: Thermal resistance and Table 5: On/off states accordingly. Updated Table 6: Dynamic, Section 4: Package mechanical data and Section 5: Packaging mechanical data. 	

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